#### TOSHIBA BI-CMOS INTEGRATED CIRCUIT SILICON MONOLITHIC

TB62003PG,TB62003FG,TB62004PG,TB62004FG TB62006PG, TB62006FG,TB62007PG,TB62007FG TB62008PG,TB62008FG, TB62009PG,TB62009FG

### 8CH DMOS TRANSISTOR ARRAY WITH GATE

TB62003PG, TB62003FG INVERTER & DMOS DRIVER

TB62004PG, TB62004FG THROUGH & DMOS DRIVER

TB62006PG, TB62006FG NAND & DMOS DRIVER

TB62007PG, TB62007FG AND & DMOS DRIVER

TB62008PG, TB62008FG NOR & DMOS DRIVER

TB62009PG, TB62009FG OR & DMOS DRIVER

The TB62003 Series are high-voltage, high-current arrays comprised of eight N-ch DMOS pairs.

This devices are a product for the Pb free(Sn-Ag).

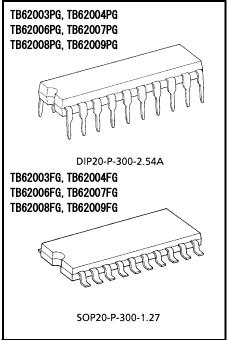
#### **FEATURES**

• Package : Type-PG DIP-20 pin

Type-FG SOP-20 pin (200 mil)

• Output rating : 35 V (Min.) / 200 mA (Max.)

• Low power

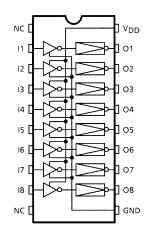


Weight

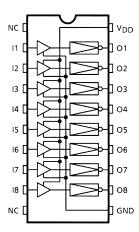
DIP20-P-300-2.54 A : 2.25 g (Typ.) SOP20-P-300-1.27 : 0.25 g (Typ.)

# **PIN CONNECTION (TOP VIEW)**

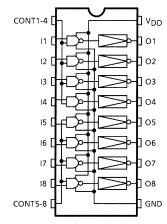
### TB62003PG / FG



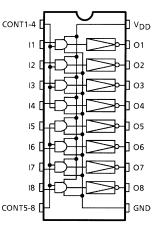
### TB62004PG / FG



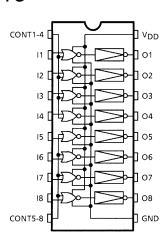
### TB62003PG / FG



TB62007PG / FG

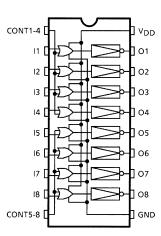


### TB62008PG / FG



TB62009PG / FG

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# **TRUTH TABLE**

## TB62006PG / FG

	INF	TU		OUTPUT		
I1~4	15~8	CONT1~4	CONT5~8	O3~4	O5~8	
Н	X	Н	X	OFF	NOT FIX	
Н	Х	L	Х	ON	NOT FIX	
L	Х	Н	Х	ON	NOT FIX	
L	Х	L	Х	ON	NOT FIX	
Х	Н	Х	Н	NOT FIX	OFF	
Х	Н	Х	L	NOT FIX	ON	
Х	L	Х	Н	NOT FIX	ON	
Х	L	X	L	NOT FIX	ON	

X: Don't Care

### TB62007PG / FG

	INF	TU		OUTPUT		
I1~4	15~8	CONT1~4	CONT5~8	O3~4	O5~8	
Н	Х	Н	X	ON	NOT FIX	
Н	X	L	Х	OFF	NOT FIX	
L	X	Н	X	OFF	NOT FIX	
L	Х	L	Х	OFF	NOT FIX	
Х	Н	Х	Н	NOT FIX	ON	
Х	Н	Х	L	NOT FIX	OFF	
Х	L	Х	Н	NOT FIX	OFF	
Х	L	Х	L	NOT FIX	OFF	

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X: Don't Care



### TB62008PG / FG

	INF	TU		OUTPUT		
I1~4	15~8	CONT1~4	CONT5~8	O3~4	O5~8	
Н	X	Н	X	OFF	NOT FIX	
Н	Х	L	Х	OFF	NOT FIX	
L	Х	Н	Х	OFF	NOT FIX	
L	Х	L	Х	ON	NOT FIX	
Х	Н	Х	Н	NOT FIX	OFF	
Х	Н	Х	L	NOT FIX	OFF	
Х	L	X	Н	NOT FIX	OFF	
Х	L	Х	L	NOT FIX	ON	

X: Don't Care

## TB62009PG / FG

	INF	PUT		OUTPUT		
11~4	15~8	CONT1~4	CONT5~8	O3~ 4	O5~8	
Н	X	Н	X	ON	NOT FIX	
Н	Х	L	Х	ON	NOT FIX	
L	Х	Н	Х	ON	NOT FIX	
L	X	L	X	OFF	NOT FIX	
Х	Н	Х	Н	NOT FIX	ON	
Х	Н	Х	L	NOT FIX	ON	
Х	L	Х	Н	NOT FIX	ON	
Х	L	Х	L	NOT FIX	OFF	

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X: Don't Care



# MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Supply Voltage		$V_{DD}$	7	V	
DC Output Voltage		V <sub>DS</sub>	-0.5~35	V	
DC Output Current		I <sub>DS</sub>	200	mA / ch	
DC Input Voltage		V <sub>IN</sub>	-0.4+V <sub>DD</sub> +0.4	V	
DC Input Current		I <sub>IN</sub>	±5	mA	
Input Diode Current		I <sub>ID</sub>	±5	mA	
Output Diode Current		lok	5	mA	
	PG	D-	1.47		
Power Dissipation	FG	P <sub>D</sub> (Note 1)	0.96 (Note 2)	W	
Operating Temperature		T <sub>opr</sub>	-40~85	°C	
Storage Temperature		T <sub>stg</sub>	-55~150	°C	

Note 1: On Glass Epoxy PCB (50  $\times$  50  $\times$  1.6 mm Cu 40%)

Note 2: Delated above 25°C in the proportion of 7.7 mW / °C (F Type)

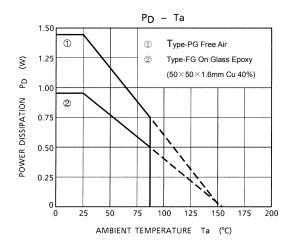
# RECOMMENDED OPERATING CONDITION (Ta = -40-85°C)

CHARACTERIS	TIC	SYMBOL	CONDITION		MIN	TYP.	MAX	UNIT
Supply Voltage Range		$V_{DD}$	_		4.5	_	5.5	V
DC Output Voltage		V <sub>DS</sub>			_	30	V	
	PG			8ch On		_	170	mA / ch
DC Output Current	FG	1	Duty 80%		_	_	90	
	PG	I <sub>DS</sub>		V <sub>DD</sub> = 5.0 V	_	_	150	
	FG		Duty 100%		_	_	80	
DC Input Voltage		V <sub>IN</sub>		_	GND	_	$V_{DD}$	V



# ELECTRICAL CHARACTERISTICS (Ta = 25°C, V<sub>DD</sub> = 5.0 V)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Output Leakage Current	I <sub>OZ</sub>	_	V <sub>DS</sub> = 35 V	_	_	50	μΑ
Low-Level Output Voltage	V <sub>DS</sub>	_	I <sub>DS</sub> = 150 mA	_	0.70	0.8	V
Low Level Output Voltage		_	I <sub>DS</sub> = 200 mA	_	0.94	1.2	V
Output Resistance	R <sub>ON</sub>	_	I <sub>DS</sub> = 200 mA	_	4.7	6.0	Ω
DC Input Current	I <sub>IN</sub>	_	V <sub>IN</sub> = GND, V <sub>IN</sub> = V <sub>DD</sub>	_	_	±1.0	μA
High-Level Input Voltage	V <sub>IN (H)</sub>	_	_	3.5	_	V <sub>DD</sub> +0.4	V
	V <sub>IN (L)</sub>	_	_	-0.4	_	1.5	
Operating Supply Current	I <sub>DDopr</sub>	_	8ch On, Output open f <sub>IN</sub> = 1MHz	_	2	_	μΑ
Output Diode Forward Voltage	V <sub>FK</sub>	_	I <sub>OK</sub> = 5 mA	_	0.6	_	V
Turn-On Delay	t <sub>ON</sub>	_	I <sub>OUT</sub> = 170 mA	_	300	_	ne
Turn-Off Delay	t <sub>OFF</sub>	_	_	_	300	_	ns
Supply Current	I <sub>DD</sub>	_	_	_	_	10	μΑ
Input Capacitance	C <sub>IN</sub>	_	_	_	15	_	pF



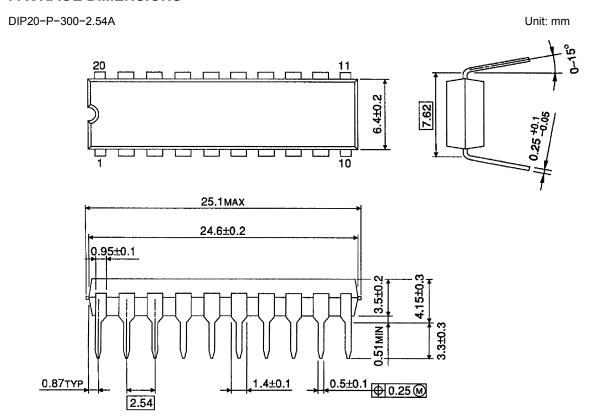
### **PRECAUTIONS for USING**

This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

Utmost care is necessary in the design of the output line,  $V_{CC}$  ( $V_{DD}$ ) and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

## **PACKAGE DIMENSIONS**

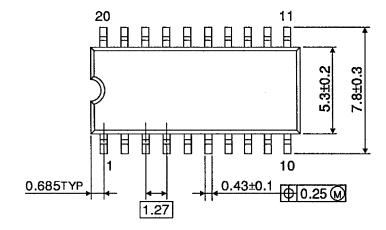


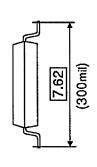
Weight: 2.25 g (Typ.)

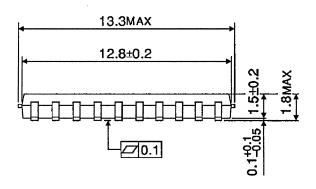
## **PACKAGE DIMENSIONS**

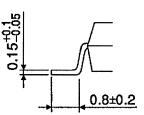
SOP20-P-300-1.27

Unit: mm









Weight: 0.25 g (Typ.)

About solderability, following conditions were confirmed

- Solderability
  - (1) Use of Sn-63Pb solder Bath
    - · solder bath temperature = 230°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux
  - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
    - · solder bath temperature = 245°C
    - · dipping time = 5 seconds
    - · the number of times = once
    - · use of R-type flux

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